



Welcome to **E-XFL.COM**

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
	Obselete
Product Status	Obsolete
Core Processor	F ² MC-16FX
Core Size	16-Bit
Speed	32MHz
Connectivity	CANbus, I ² C, LINbus, SCI, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	64
Program Memory Size	160KB (160K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 21x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb96f635rbpmc-gse2



Pin name	Feature	Description					
TXn	CAN	CAN interface n TX output pin					
Vcc	Supply	Power supply pin					
Vss	Supply	Power supply pin					
WOT	RTC	Real Time clock output pin					
WOT_R	RTC	Relocated Real Time clock output pin					
X0	Clock	Oscillator input pin					
X0A	Clock	Subclock Oscillator input pin					
X1	Clock	Oscillator output pin					
X1A	Clock	Subclock Oscillator output pin					
ZINn	QPRC	Quadrature Position/Revolution Counter Unit n input pin					



Туре	Circuit	Remarks
F	P-ch N-ch	Power supply input protection circuit
G	P-ch N-ch	 A/D converter ref+ (AVRH) power supply input pin with protection circuit Without protection circuit against V_{CC} for pins AVRH
Н	Pull-up control P-ch P-ch Pout N-ch Nout Automotive input	 CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) Automotive input with input shutdown function Programmable pull-up resistor
	P-ch P-ch Pout N-ch Nout Hysteresis input for input shutdown Analog input	 CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) CMOS hysteresis input with input shutdown function Programmable pull-up resistor Analog input



9. User ROM Memory Map For Flash Devices

		MB96F633	MB96F635	MB96F636	MB96F637	
CPU mode address	Flash memory mode address	Flash size 64.5KB + 32KB	Flash size 128.5KB + 32KB	Flash size 256.5KB + 32KB	Flash size 384.5KB + 32KB	
FF:FFFF _H FF:0000 _H	3F:FFFF _H 3F:0000 _H	SA39 - 64KB	SA39 - 64KB	SA39 - 64KB	SA39 - 64KB	
FE:FFFF _H FE:0000 _H	3E:FFFF _H 3E:0000 _H		SA38 - 64KB	SA38 - 64KB	SA38 - 64KB	
FD:FFFF _H FD:0000 _H	3D:FFFF _H 3D:0000 _H			SA37 - 64KB	SA37 - 64KB	
FC:FFFF _H FC:0000 _H	3C:FFFF _H 3C:0000 _H			SA36 - 64KB	SA36 - 64KB	Bank A of Flash A
FB:FFFF _H FB:0000 _H	3B:FFFF _H 3B:0000 _H				SA35 - 64KB	
FA:FFFF _H FA:0000 _H	3A:FFFF _H 3A:0000 _H				SA34 - 64KB	
PF:A000 _H	45-05-55	Reserved	Reserved	Reserved	Reserved	
DF:9FFF _H DF:8000 _H	1F:9FFF _H 1F:8000 _H	SA4 - 8KB	SA4 - 8KB	SA4 - 8KB	SA4 - 8KB	
DF:7FFF _H DF:6000 _H	1F:7FFF _H 1F:6000 _H	SA3 - 8KB	SA3 - 8KB	SA3 - 8KB	SA3 - 8KB	Bank B of Flash A
DF:5FFF _H DF:4000 _H	1F:5FFF _H 1F:4000 _H	SA2 - 8KB	SA2 - 8KB	SA2 - 8KB	SA2 - 8KB	Bank B OI Flash A
DF:3FFF _H DF:2000 _H	1F:3FFF _H 1F:2000 _H	SA1 - 8KB	SA1 - 8KB	SA1 - 8KB	SA1 - 8KB	
DF:1FFF _H DF:0000 _H	1F:1FFF _H 1F:0000 _H	SAS - 512B*	SAS - 512B*	SAS - 512B*	SAS - 512B*	Bank A of Flash A
DE:FFFF _H DE:0000 _H	*****	Reserved	Reserved	Reserved	Reserved	

^{*:} Physical address area of SAS-512B is from DF:0000 $_{\rm H}$ to DF:01FF $_{\rm H}$. Others (from DF:0200 $_{\rm H}$ to DF:1FFF $_{\rm H}$) is mirror area of SAS-512B. Sector SAS contains the ROM configuration block RCBA at CPU address DF:0000 $_{\rm H}$ -DF:01FF $_{\rm H}$. SAS can not be used for E 2 PROM emulation.



10. Serial Programming Communication Interface

USART pins for Flash serial programming (MD = 0, DEBUG I/F = 0, Serial Communication mode)

MB96630									
Pin Number	USART Number	Normal Function							
5		SIN0							
6	USART0	SOT0							
7		SCK0							
37		SIN2							
38	USART2	SOT2							
39		SCK2							
68		SIN4							
69	USART4	SOT4							
70		SCK4							



Vector number	Offset in vector table	Vector name	Cleared by DMA	Index in ICR to program	Description
40	35C _H	PPG2	Yes	40	Programmable Pulse Generator 2
41	358H	PPG3	Yes	41	Programmable Pulse Generator 3
42	354H	PPG4	Yes	42	Programmable Pulse Generator 4
43	350H	-	-	43	Reserved
44	34CH	PPG6	Yes	44	Programmable Pulse Generator 6
45	348H	PPG7	Yes	45	Programmable Pulse Generator 7
46	344H	PPG8	Yes	46	Programmable Pulse Generator 8
47	340H	PPG9	Yes	47	Programmable Pulse Generator 9
48	33CH	PPG10	Yes	48	Programmable Pulse Generator 10
49	338H	PPG11	Yes	49	Programmable Pulse Generator 11
50	334H	PPG12	Yes	50	Programmable Pulse Generator 12
51	330H	PPG13	Yes	51	Programmable Pulse Generator 13
52	32CH	PPG14	Yes	52	Programmable Pulse Generator 14
53	328H	PPG15	Yes	53	Programmable Pulse Generator 15
54	324H	-	-	54	Reserved
55	320H	-	-	55	Reserved
56	31CH	-	-	56	Reserved
57	318H	-	-	57	Reserved
58	314H	RLT0	Yes	58	Reload Timer 0
59	310H	RLT1	Yes	59	Reload Timer 1
60	30CH	-	-	60	Reserved
61	308H	-	-	61	Reserved
62	304H	-	-	62	Reserved
63	300H	-	-	63	Reserved
64	2FCH	RLT6	Yes	64	Reload Timer 6
65	2F8H	ICU0	Yes	65	Input Capture Unit 0
66	2F4H	ICU1	Yes	66	Input Capture Unit 1
67	2F0H	-	-	67	Reserved
68	2ECH	-	-	68	Reserved
69	2E8H	ICU4	Yes	69	Input Capture Unit 4
70	2E4H	ICU5	Yes	70	Input Capture Unit 5
71	2E0H	ICU6	Yes	71	Input Capture Unit 6
72	2DCH	ICU7	Yes	72	Input Capture Unit 7
73	2D8H	-	-	73	Reserved
74	2D4H	ICU9	Yes	74	Input Capture Unit 9
75	2D0H	-	-	75	Reserved
76	2CCH	-	-	76	Reserved
77	2C8H	OCU0	Yes	77	Output Compare Unit 0
78	2C4H	OCU1	Yes	78	Output Compare Unit 1
79	2C0H	OCU2	Yes	79	Output Compare Unit 2
80	2BCH	OCU3	Yes	80	Output Compare Unit 3
81	2B8H	OCU4	Yes	81	Output Compare Unit 4



Vector number	Offset in vector table	Vector name	Cleared by DMA	Index in ICR to program	Description		
124	20CH	-	-	124	Reserved		
125	208H	-	-	125	Reserved		
126	204H	-	-	126	Reserved		
127	200H	-	-	127	Reserved		
128	1FCH	-	-	128	Reserved		
129	1F8H	-	-	129	Reserved		
130	1F4H	-	-	130	Reserved		
131	1F0H	-	-	131	Reserved		
132	1ECH	-	-	132	Reserved		
133	1E8H	FLASHA	Yes	133	Flash memory A interrupt		
134	1E4H	-	-	134	Reserved		
135	1E0H	-	-	135	Reserved		
136	1DCH	-	-	136	Reserved		
137	1D8H	QPRC0	Yes	137	Quadrature Position/Revolution counter 0		
138	1D4H	QPRC1	Yes	138	Quadrature Position/Revolution counter 1		
139	1D0H	ADCRC0	No	139	A/D Converter 0 - Range Comparator		
140	1CCH	-	-	140	Reserved		
141	1C8H	-	-	141	Reserved		
142	1C4H	-	-	142	Reserved		
143	1C0H	-	-	143	Reserved		

Page 27 of 69



■Precautions Related to Usage of Devices

Cypress semiconductor devices are intended for use in standard applications (computers, office automation and other office equipment, industrial, communications, and measurement equipment, personal or household devices, etc.).

CAUTION: Customers considering the use of our products in special applications where failure or abnormal operation may directly affect human lives or cause physical injury or property damage, or where extremely high levels of reliability are demanded (such as aerospace systems, atomic energy controls, sea floor repeaters, vehicle operating controls, medical devices for life support, etc.) are requested to consult with sales representatives before such use. The company will not be responsible for damages arising from such use without prior approval.

12.2 Precautions for Package Mounting

Package mounting may be either lead insertion type or surface mount type. In either case, for heat resistance during soldering, you should only mount under Cypress's recommended conditions. For detailed information about mount conditions, contact your sales representative.

■Lead Insertion Type

Mounting of lead insertion type packages onto printed circuit boards may be done by two methods: direct soldering on the board, or mounting by using a socket.

Direct mounting onto boards normally involves processes for inserting leads into through-holes on the board and using the flow soldering (wave soldering) method of applying liquid solder. In this case, the soldering process usually causes leads to be subjected to thermal stress in excess of the absolute ratings for storage temperature. Mounting processes should conform to Cypress recommended mounting conditions.

If socket mounting is used, differences in surface treatment of the socket contacts and IC lead surfaces can lead to contact deterioration after long periods. For this reason it is recommended that the surface treatment of socket contacts and IC leads be verified before mounting.

■Surface Mount Type

Surface mount packaging has longer and thinner leads than lead-insertion packaging, and therefore leads are more easily deformed or bent. The use of packages with higher pin counts and narrower pin pitch results in increased susceptibility to open connections caused by deformed pins, or shorting due to solder bridges.

You must use appropriate mounting techniques. Cypress recommends the solder reflow method, and has established a ranking of mounting conditions for each product. Users are advised to mount packages in accordance with Cypress ranking of recommended conditions.

■Lead-Free Packaging

CAUTION: When ball grid array (BGA) packages with Sn-Ag-Cu balls are mounted using Sn-Pb eutectic soldering, junction strength may be reduced under some conditions of use.

■ Storage of Semiconductor Devices

Because plastic chip packages are formed from plastic resins, exposure to natural environmental conditions will cause absorption of moisture. During mounting, the application of heat to a package that has absorbed moisture can cause surfaces to peel, reducing moisture resistance and causing packages to crack. To prevent, do the following:

- 1. Avoid exposure to rapid temperature changes, which cause moisture to condense inside the product. Store products in locations where temperature changes are slight.
- Use dry boxes for product storage. Products should be stored below 70% relative humidity, and at temperatures between 5°C and 30°C.
 - When you open Dry Package that recommends humidity 40% to 70% relative humidity.
- 3. When necessary, Cypress packages semiconductor devices in highly moisture-resistant aluminum laminate bags, with a silica gel desiccant. Devices should be sealed in their aluminum laminate bags for storage.
- 4. Avoid storing packages where they are exposed to corrosive gases or high levels of dust.

■Baking

Packages that have absorbed moisture may be de-moisturized by baking (heat drying). Follow the Cypress recommended conditions for baking.

Condition: 125°C/24 h

Document Number: 002-04719 Rev.*A



■Static Electricity

Because semiconductor devices are particularly susceptible to damage by static electricity, you must take the following precautions:

- 1. Maintain relative humidity in the working environment between 40% and 70%. Use of an apparatus for ion generation may be needed to remove electricity.
- 2. Electrically ground all conveyors, solder vessels, soldering irons and peripheral equipment.
- Eliminate static body electricity by the use of rings or bracelets connected to ground through high resistance (on the level of 1 MΩ).
 - Wearing of conductive clothing and shoes, use of conductive floor mats and other measures to minimize shock loads is recommended.
- 4. Ground all fixtures and instruments, or protect with anti-static measures.
- 5. Avoid the use of styrofoam or other highly static-prone materials for storage of completed board assemblies.

12.3 Precautions for Use Environment

Reliability of semiconductor devices depends on ambient temperature and other conditions as described above.

For reliable performance, do the following:

- 1. Humidity
 - Prolonged use in high humidity can lead to leakage in devices as well as printed circuit boards. If high humidity levels are anticipated, consider anti-humidity processing.
- 2. Discharge of Static Electricity
 - When high-voltage charges exist close to semiconductor devices, discharges can cause abnormal operation. In such cases, use anti-static measures or processing to prevent discharges.
- 3. Corrosive Gases, Dust, or Oil
 - Exposure to corrosive gases or contact with dust or oil may lead to chemical reactions that will adversely affect the device. If you use devices in such conditions, consider ways to prevent such exposure or to protect the devices.
- 4. Radiation, Including Cosmic Radiation
 - Most devices are not designed for environments involving exposure to radiation or cosmic radiation. Users should provide shielding as appropriate.
- 5. Smoke, Flame
 - CAUTION: Plastic molded devices are flammable, and therefore should not be used near combustible substances. If devices begin to smoke or burn, there is danger of the release of toxic gases.

Customers considering the use of Cypress products in other special environmental conditions should consult with sales representatives.

Document Number: 002-04719 Rev.*A



14.2 Recommended Operating Conditions

 $(V_{SS} = AV_{SS} = 0V)$

Parameter	Symbol		Value		Unit	Remarks
Faranietei	Syllibol	Min	Тур	Max	Ollit	Kemarks
Power supply	V _{CC} , AV _{CC}	2.7	-	5.5	V	
voltage	VCC, AVCC	2.0	-	- 5.5 V		Maintains RAM data in stop mode
Smoothing capacitor at C pin	Cs	0.5	1.0 to 3.9	4.7	μF	$\begin{array}{l} 1.0\mu F \text{ (Allowance within} \pm 50\%) \\ 3.9\mu F \text{ (Allowance within} \pm 20\%) \\ \text{Please use the ceramic capacitor or the capacitor of the frequency response of this level.} \\ \text{The smoothing capacitor at V_{CC} must use the one of a capacity value that is larger than C_{S}.} \end{array}$

WARNING

The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure. No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.



Parameter	Symbol	Pin	Conditions		Value		Unit	Remarks
Parameter	Symbol	name	Conditions	Min	Тур	Max	Ullit	Remarks
			PLL Sleep mode with		8.5	-	mA	$T_A = +25^{\circ}C$
	I _{CCSPLL}		CLKS1/2 = CLKP1/2 = 32MHz (CLKRC and CLKSC	-	-	14	mA	$T_A = +105$ °C
			stopped)	-	-	15.5	mA	$T_A = +125$ °C
			Main Sleep mode with CLKS1/2 = CLKP1/2 =	-	1	-	mA	$T_A = +25^{\circ}C$
	I _{CCSMAIN}		4MHz, SMCR:LPMSS = 0	-	-	4.5	mA	$T_A = +105$ °C
		Vcc	(CLKPLL, CLKRC and CLKSC stopped)	-	-	6	mA	$T_A = +125$ °C
	I _{CCSRCH}		RC Sleep mode with CLKS1/2 = CLKP1/2 = CLKRC = 2MHz, SMCR:LPMSS = 0 (CLKMC, CLKPLL and CLKSC stopped)	-	0.6	-	mA	$T_A = +25^{\circ}C$
Power supply current in Sleep modes*1				-	-	3.8	mA	$T_A = +105$ °C
				-	-	5.3	mA	$T_A = +125^{\circ}C$
			RC Sleep mode with CLKS1/2	-	0.07	-	mA	$T_A = +25^{\circ}C$
	I _{CCSRCL}		= CLKP1/2 = CLKRC = 100kHz (CLKMC, CLKPLL and	-	-	2.8	mA	$T_A = +105$ °C
			CLKSC stopped)	-	-	4.3	mA	$T_A = +125^{\circ}C$
	I _{CCSSUB}		Sub Sleep mode with	-	0.04	-	mA	$T_A = +25^{\circ}C$
			CLKS1/2 = CLKP1/2 = 32kHz, (CLKMC, CLKPLL and	-	-	2.5	mA	$T_A = +105$ °C
			CLKRC stopped)	-	-	4	mA	$T_A = +125$ °C



14.3.2 Pin Characteristics

 $(V_{CC} = AV_{CC} = 2.7V \text{ to } 5.5V, V_{SS} = AV_{SS} = 0V, T_A = -40^{\circ}\text{C to } + 125^{\circ}\text{C})$

Parameter	Symbol	Pin name	Conditions		Value		Unit	Remarks
rarameter	Syllibol	Fin name	Conditions	Min	Тур	Max	Onit	Remarks
	W	Port inputs	-	V _{CC} × 0.7	-	V _{CC} + 0.3	V	CMOS Hysteresis input
	V_{IH}	Pnn_m	-	$V_{CC} \times 0.8$	-	V _{CC} + 0.3	V	AUTOMOTIVE Hysteresis input
	V _{IHX0S}	X0	External clock in "Fast Clock Input mode"	VD × 0.8	-	VD	V	VD=1.8V±0.15V
"H" level input voltage	V _{IHX0AS}	X0A	External clock in "Oscillation mode"	V _{CC} × 0.8	-	V _{CC} + 0.3	V	
	V _{IHR}	RSTX	-	V _{CC} × 0.8	-	V _{CC} + 0.3	V	CMOS Hysteresis input
	V _{IHM}	MD	-	V _{CC} - 0.3	-	V _{CC} + 0.3	V	CMOS Hysteresis input
	V _{IHD}	DEBUG I/F	-	2.0	-	V _{CC} + 0.3	V	TTL Input
	V	Port inputs	-	V _{SS} - 0.3	-	V _{CC} × 0.3	V	CMOS Hysteresis input
	V _{IL}	Pnn_m	-	V _{SS} - 0.3	-	$V_{CC} \times 0.5$	V	AUTOMOTIVE Hysteresis input
	V _{ILX0S}	X0	External clock in "Fast Clock Input mode"	V _{SS}	-	VD × 0.2	V	VD=1.8V±0.15V
"L" level input voltage	V _{ILX0AS}	X0A	External clock in "Oscillation mode"	V _{SS} - 0.3	-	V _{CC} × 0.2	V	
	V _{ILR}	RSTX	-	V _{SS} - 0.3	-	V _{CC} × 0.2	V	CMOS Hysteresis input
	V _{ILM}	MD	-	V _{SS} - 0.3	-	V _{SS} + 0.3	V	CMOS Hysteresis input
	V _{ILD}	DEBUG I/F	-	V _{SS} - 0.3	-	0.8	V	TTL Input
"H" level	V_{OH4}	4mA type	$ \begin{aligned} 4.5 & \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V} \\ & \text{I}_{\text{OH}} = -4 \text{mA} \\ & 2.7 & \text{V} \leq \text{V}_{\text{CC}} < 4.5 \text{V} \\ & \text{I}_{\text{OH}} = -1.5 \text{mA} \end{aligned} $	V _{CC} - 0.5	-	V _{CC}	V	
output voltage	V_{OH3}	3mA type	$\begin{split} I_{OH} &= -1.5 mA \\ 4.5 V &\leq V_{CC} \leq 5.5 V \\ I_{OH} &= -3 mA \\ 2.7 V &\leq V_{CC} < 4.5 V \\ I_{OH} &= -1.5 mA \end{split}$	V _{CC} - 0.5	-	V _{CC}	V	
"L" level	V_{OL4}	4mA type	$4.5V \le V_{CC} \le 5.5V$ $I_{OL} = +4mA$ $2.7V \le V_{CC} < 4.5V$	-	-	0.4	v	
output voltage	V _{OL3}	3mA type	$\begin{split} &I_{OL} = +1.7 mA \\ &2.7 V \leq V_{CC} < 5.5 V \\ &I_{OL} = +3 mA \\ &V_{CC} = 2.7 V \end{split}$	-	-	0.4	V	
	V _{OLD}	DEBUG I/F	$V_{CC} = 2.7V$ $I_{OL} = +25mA$	0	-	0.25	V	



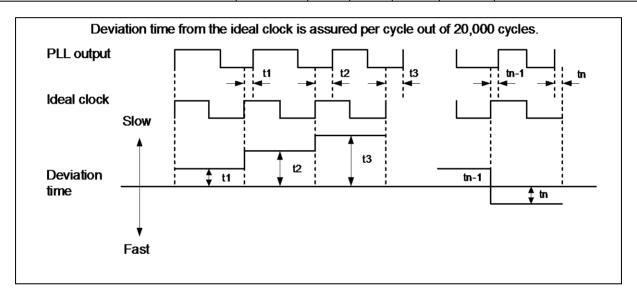
Parameter	Symbol	Pin name	name Conditions Value				Unit	Remarks
Parameter	Syllibol	Fill liaille	Conditions	Min	Тур	Max	Onit	Remarks
Input leak current	I_{IL}	Pnn_m	$ \begin{aligned} &V_{SS} < V_{I} < V_{CC} \\ &AV_{SS} < V_{I} < \\ &AV_{CC}, AVRH \end{aligned} $	- 1	-	+ 1	μА	
Pull-up resistance value	R _{PU}	Pnn_m	$V_{CC} = 5.0V \pm 10\%$	25	50	100	kΩ	
Input capacitance	C _{IN}	Other than C, Vcc, Vss, AVcc, AVss, AVRH	-	-	5	15	pF	



14.4.5 Operating Conditions of PLL

 $(V_{CC} = AV_{CC} = 2.7V \text{ to } 5.5V, V_{SS} = AV_{SS} = 0V, T_A = -40^{\circ}\text{C to } + 125^{\circ}\text{C})$

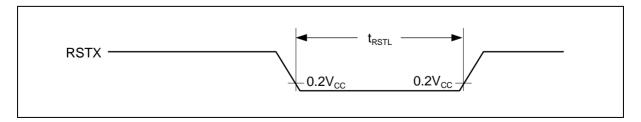
Parameter	Symbol	Value			Unit	Remarks	
raidiffetei	Symbol	Min	Тур	Max	Onit	Kemarks	
PLL oscillation stabilization wait time	t _{LOCK}	1	-	4	ms	For CLKMC = 4MHz	
PLL input clock frequency	f _{PLLI}	4	-	8	MHz		
PLL oscillation clock frequency	f _{CLKVCO}	56	-	108	MHz	Permitted VCO output frequency of PLL (CLKVCO)	
PLL phase jitter	t _{PSKEW}	-5	-	+5	ns	For CLKMC (PLL input clock) ≥ 4MHz	



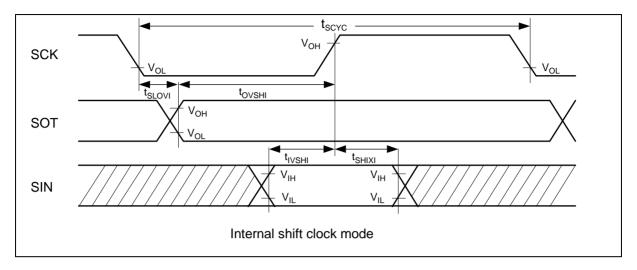
14.4.6 Reset Input

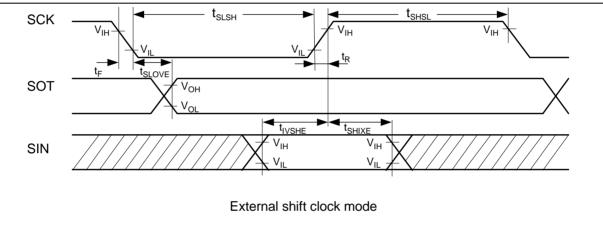
(V_{CC} = AV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = 0V,
$$T_A$$
 = -40°C to + 125°C)

Parameter	Symbol	Pin name	Value		Unit	
rannotor		1 III IIdilic	Min	Max	Oille	
Reset input time		RSTX	10	-	μs	
Rejection of reset input time	trstl		1	-	μS	











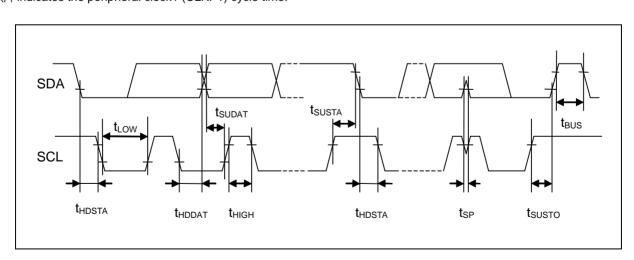
14.4.10 I²C Timing

 $(V_{CC} = AV_{CC} = 2.7V \text{ to } 5.5V, V_{SS} = AV_{SS} = 0V, T_A = -40^{\circ}\text{C to } + 125^{\circ}\text{C})$

Parameter	Symbol	Conditions	Typical mode		High-speed mode*4		Unit
rai ailletei			Min	Max	Min	Max	Onit
SCL clock frequency	f _{SCL}		0	100	0	400	kHz
(Repeated) START condition hold							
time	t _{HDSTA}		4.0	-	0.6	-	μS
$SDA \downarrow \rightarrow SCL \downarrow$							
SCL clock "L" width	t _{LOW}	1	4.7	-	1.3	-	μS
SCL clock "H" width	t _{HIGH}		4.0	-	0.6	-	μS
(Repeated) START condition setup							
time	tsusta	$ \begin{array}{c} t_{\text{SUSTA}} \\ \hline \\ t_{\text{HDDAT}} \end{array} \qquad \begin{array}{c} C_{\text{L}} = 50 \text{pF}, \\ R = (\text{Vp/I}_{\text{OL}})^{*1} \end{array} $	4.7	-	0.6	-	μS
SCL ↑ → SDA ↓							
Data hold time	4		0	3.45* ²	0	0.9*3	_
$SCL \downarrow \rightarrow SDA \downarrow \uparrow$	LHDDAT		U	3.43	0	0.9	μS
Data setup time	4		250	_	100	_	no
$SDA \downarrow \uparrow \rightarrow SCL \uparrow$	t _{SUDAT}		250	_	100	-	ns
STOP condition setup time	4		4.0		0.6		
$\operatorname{SCL} \uparrow \to \operatorname{SDA} \uparrow$	t _{SUSTO}		4.0	-	0.6	_	μS
Bus free time between							
"STOP condition" and	t _{BUS}		4.7	-	1.3	-	μS
"START condition"							
Dulge width of enilses which will be				(4.4.5)		(4.4.5)	
Pulse width of spikes which will be	t _{SP}	-	0	(1-1.5) ×	0	(1-1.5) ×	ns
suppressed by input noise filter				t _{CLKP1} *°		t _{CLKP1} *5	

 $^{^{\}star 1}$: R and C_L represent the pull-up resistance and load capacitance of the SCL and SDA lines, respectively. Vp indicates the power supply voltage of the pull-up resistance and I_{OL} indicates V_{OL} guaranteed current.

^{*5:} t_{CLKP1} indicates the peripheral clock1 (CLKP1) cycle time.

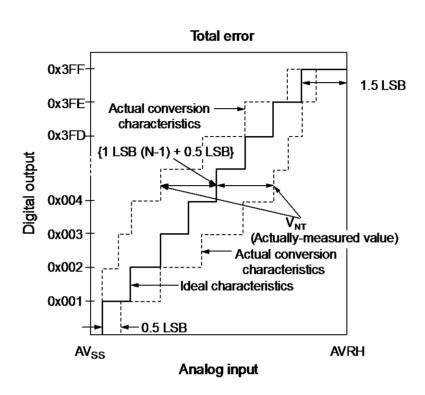


^{*2:} The maximum t_{HDDAT} only has to be met if the device does not extend the "L" width (t_{LOW}) of the SCL signal.

^{*3:} A high-speed mode I²C bus device can be used on a standard mode I²C bus system as long as the device satisfies the requirement of "t_{SUDAT} ≥ 250ns".

^{*4:} For use at over 100kHz, set the peripheral clock1 (CLKP1) to at least 6MHz.





1LSB (Ideal value) =
$$\frac{AVRH - AV_{SS}}{1024}$$
 [V]

Total error of digital output N =
$$\frac{V_{NT} - \{1LSB \times (N-1) + 0.5LSB\}}{1LSB}$$

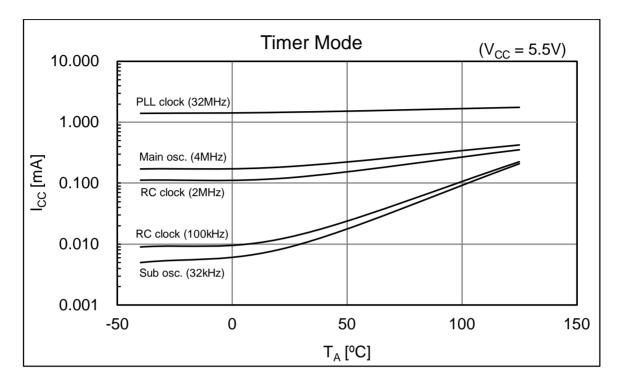
N : A/D converter digital output value.

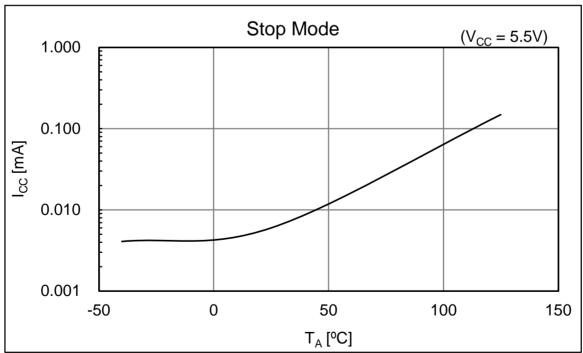
 V_{NT} : Voltage at which the digital output changes from 0x(N + 1) to 0xN.

V_{OT} (Ideal value) = AV_{SS} + 0.5LSB[V] V_{FST} (Ideal value) = AVRH - 1.5LSB[V]



■MB96F637







16. Ordering Information

MCU with CAN controller

Part number	Flash memory	Package*	
MB96F633RBPMC-GSE1	Flash A	80-pin plastic LQFP	
MB96F633RBPMC-GSE2	(96.5KB)	(FPT-80P-M21)	
MB96F635RBPMC-GSE1	Flash A	80-pin plastic LQFP	
MB96F635RBPMC-GSE2	(160.5KB)	(FPT-80P-M21)	
MB96F636RBPMC-GSE1	Flash A	80-pin plastic LQFP	
MB96F636RBPMC-GSE2	(288.5KB)	(FPT-80P-M21)	
MB96F637RBPMC-GSE1	Flash A	80-pin plastic LQFP	
MB96F637RBPMC-GSE2	(416.5KB)	(FPT-80P-M21)	

^{*:} For details about package, see "Package Dimension".

MCU without CAN controller

Part number	Flash memory	Package*
MB96F633ABPMC-GSE1	Flash A	80-pin plastic LQFP
MB96F633ABPMC-GSE2	(96.5KB)	(FPT-80P-M21)
MB96F635ABPMC-GSE1	Flash A	80-pin plastic LQFP
MB96F635ABPMC-GSE2	(160.5KB)	(FPT-80P-M21)

^{*:} For details about package, see "Package Dimension".



Page	Section	Change Results
	Interrupt Vector Table	Changed the Description of CALLV0 to CALLV7 Reserved →
		CALLV instruction
		Changed the Description of RESET Reserved
		→ -
21		Reset vector
		Changed the Description of INT9 Reserved →
		INT9 instruction
		Changed the Description of EXCEPTION Reserved
		\rightarrow
		Undefined instruction execution
		Changed the Vector name of Vector number 64 PPGRLT
		→ RLT6
22		Changed the Description of Vector number 64
		Reload Timer 6 can be used as PPG clock source →
		Reload Timer 6
25 to 28	Handling Precautions	Added a section
1	Handling Devices	Added the description to "3. External clock usage"
		(3) Opposite phase external clock
		Changed the description in "7. Turn on sequence of power supply to A/D converter and analog inputs"
30		In this case, the voltage must not exceed AVRH or AV_{CC}
		In this case, AVRH must not exceed AV _{CC} . Input voltage for ports shared with analog input ports also must not exceed AV _{CC}
31	-	Added the description "12. Mode Pin (MD)"
<u> </u>	Electrical Characteristics	Changed the annotation *4
	Absolute Maximum Ratings	Note that if the +B input is applied during power-on, the power supply is provided from the pins and the resulting supply voltage may not be sufficient to operate the Power reset (except devices with persistent
33		low voltage reset in internal vector mode). →
		Note that if the +B input is applied during power-on, the power supply
		is provided from the pins and the resulting supply voltage may not be sufficient to operate the Power reset.
	1. Absolute Maximum Ratings	Added the annotation *4
		The DEBUG I/F pin has only a protective diode against V _{SS} . Hence it
33		is only permitted to input a negative clamping current (4mA). For
		protection against positive input voltages, use an external clamping diode which limits the input voltage to maximum 6.0V.
	2. Recommended Operating Conditions	Added the Value and Remarks to "Power supply voltage" Min: 2.0V
		Typ: -
		Max: 5.5V
		Remarks: Maintains RAM data in stop mode
35		Changed the Value of "Smoothing capacitor at C pin"
		Typ: 1.0μ F $\rightarrow 1.0\mu$ F to 3.9μ F
		Max: $1.5\mu F \rightarrow 4.7\mu F$ Changed the Remarks of "Smoothing capacitor at C pin"
		Deleted "(Target value)"
		Added "3.9µF (Allowance within ± 20%)"